

# SKKT 92, SKKH 92, SKKT 92B



SEMIPACK® 1

## Thyristor / Diode Modules

### SKKT 92

### SKKT 92B

### SKKH 92

### Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

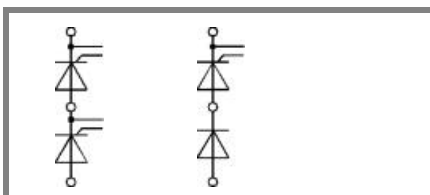
### Typical Applications

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

<sup>1)</sup> See the assembly instructions

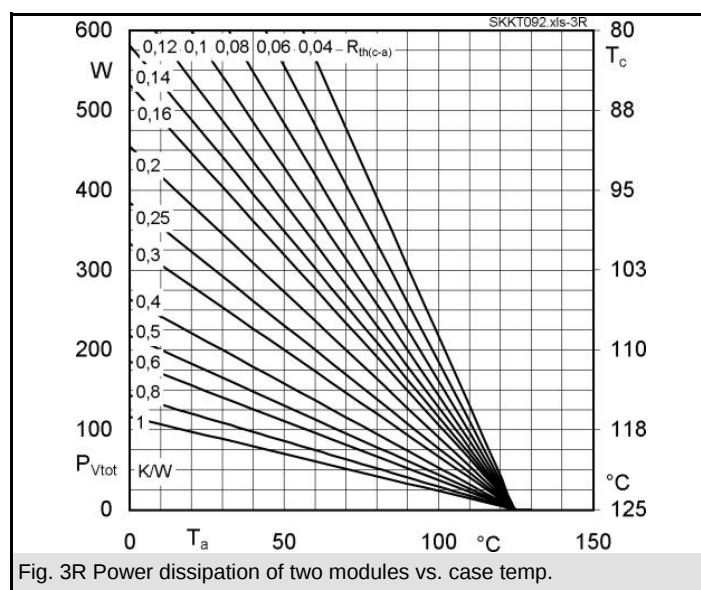
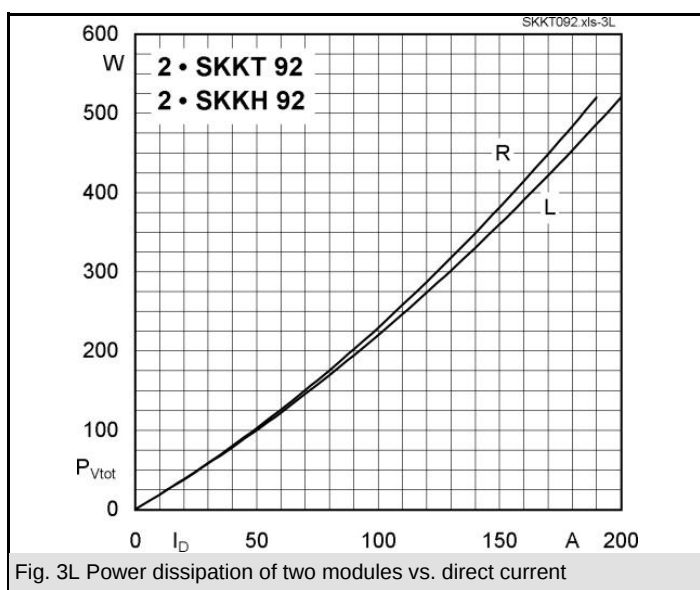
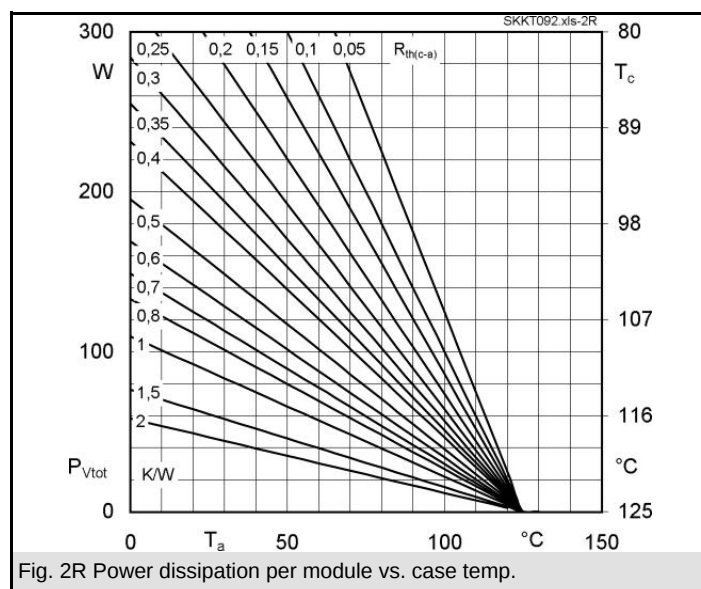
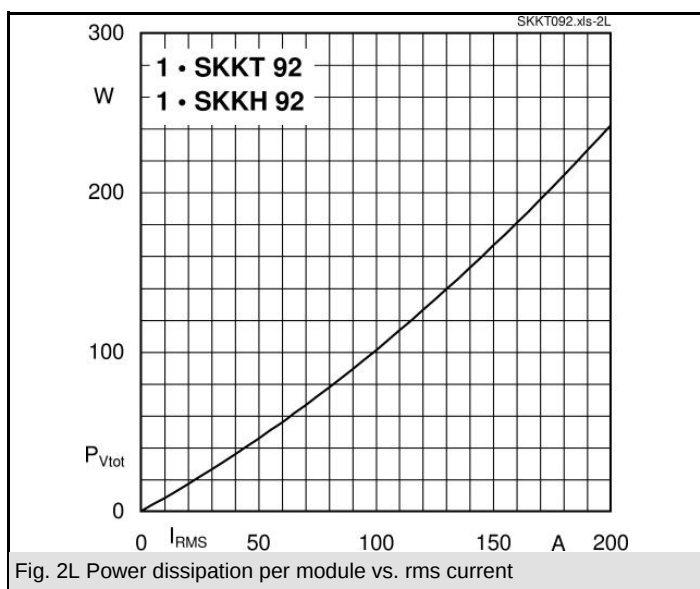
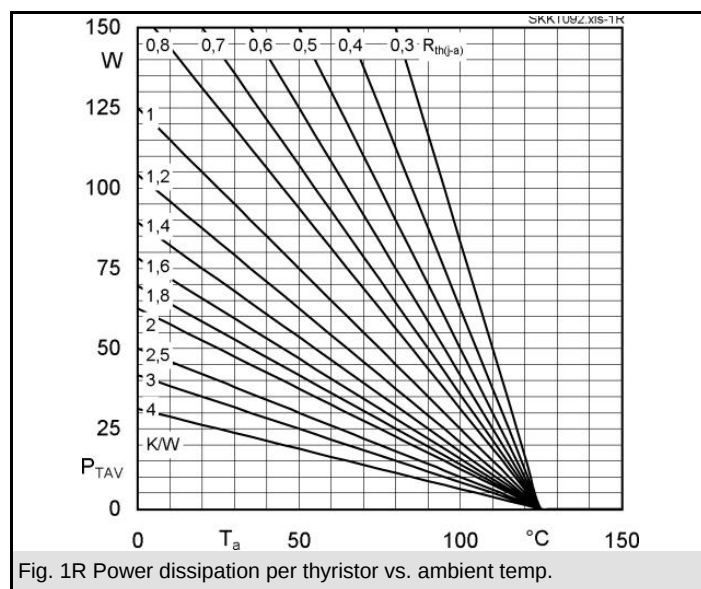
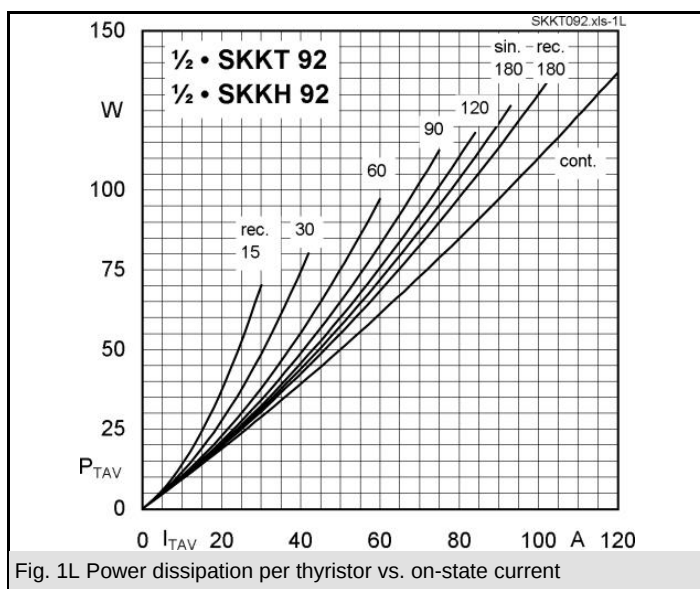
| $V_{RSM}$<br>V | $V_{RRM}, V_{DRM}$<br>V | $I_{TRMS} = 150$ A (maximum value for continuous operation)<br>$I_{TAV} = 95$ A (sin. 180; $T_c = 85$ °C) |             |             |
|----------------|-------------------------|-----------------------------------------------------------------------------------------------------------|-------------|-------------|
| 900            | 800                     | SKKT 92/08E                                                                                               | SKKT 92B08E | SKKH 92/08E |
| 1300           | 1200                    | SKKT 92/12E                                                                                               | SKKT 92B12E | SKKH 92/12E |
| 1500           | 1400                    | SKKT 92/14E                                                                                               | SKKT 92B14E | SKKH 92/14E |
| 1700           | 1600                    | SKKT 92/16E                                                                                               | SKKT 92B16E | SKKH 92/16E |
| 1900           | 1800                    | SKKT 92/18E                                                                                               | SKKT 92B18E | SKKH 92/18E |

| Symbol           | Conditions                                              | Values                 | Units |
|------------------|---------------------------------------------------------|------------------------|-------|
| $I_{TAV}$        | sin. 180; $T_c = 85$ (100) °C                           | 95 (68)                | A     |
| $I_D$            | P3/180; $T_a = 45$ °C; B2 / B6                          | 70 / 85                | A     |
|                  | P3/180F; $T_a = 35$ °C; B2 / B6                         | 140 / 175              | A     |
| $I_{RMS}$        | P3/180F; $T_a = 35$ °C; W1 / W3                         | 190 / 3 * 135          | A     |
| $I_{TSM}$        | $T_{vj} = 25$ °C; 10 ms                                 | 2000                   | A     |
|                  | $T_{vj} = 125$ °C; 10 ms                                | 1750                   | A     |
| $i^2t$           | $T_{vj} = 25$ °C; 8,3 ... 10 ms                         | 20000                  | A²s   |
|                  | $T_{vj} = 125$ °C; 8,3 ... 10 ms                        | 15000                  | A²s   |
| $V_T$            | $T_{vj} = 25$ °C; $I_T = 300$ A                         | max. 1,65              | V     |
| $V_{T(TO)}$      | $T_{vj} = 125$ °C                                       | max. 0,9               | V     |
| $r_T$            | $T_{vj} = 125$ °C                                       | max. 2                 | mΩ    |
| $I_{DD}, I_{RD}$ | $T_{vj} = 125$ °C; $V_{RD} = V_{RRM}, V_{DD} = V_{DRM}$ | max. 20                | mA    |
| $t_{gd}$         | $T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs       | 1                      | μs    |
| $t_{gr}$         | $V_D = 0,67 * V_{DRM}$                                  | 2                      | μs    |
| $(di/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | max. 150               | A/μs  |
| $(dv/dt)_{cr}$   | $T_{vj} = 125$ °C                                       | max. 1000              | V/μs  |
| $t_q$            | $T_{vj} = 125$ °C                                       | 100                    | μs    |
| $I_H$            | $T_{vj} = 25$ °C; typ. / max.                           | 150 / 250              | mA    |
| $I_L$            | $T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.             | 300 / 600              | mA    |
| $V_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | min. 3                 | V     |
| $I_{GT}$         | $T_{vj} = 25$ °C; d.c.                                  | min. 150               | mA    |
| $V_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | max. 0,25              | V     |
| $I_{GD}$         | $T_{vj} = 125$ °C; d.c.                                 | max. 6                 | mA    |
| $R_{th(j-c)}$    | cont.; per thyristor / per module                       | 0,28 / 0,14            | K/W   |
| $R_{th(j-c)}$    | sin. 180; per thyristor / per module                    | 0,3 / 0,15             | K/W   |
| $R_{th(j-c)}$    | rec. 120; per thyristor / per module                    | 0,32 / 0,16            | K/W   |
| $R_{th(c-s)}$    | per thyristor / per module                              | 0,2 / 0,1              | K/W   |
| $T_{vj}$         |                                                         | - 40 ... + 125         | °C    |
| $T_{stg}$        |                                                         | - 40 ... + 125         | °C    |
| $V_{isol}$       | a. c. 50 Hz; r.m.s.; 1 s / 1 min.                       | 3600 / 3000            | V~    |
| $M_s$            | to heatsink                                             | 5 ± 15 % <sup>1)</sup> | Nm    |
| $M_t$            | to terminals                                            | 3 ± 15 %               | Nm    |
| $a$              |                                                         | 5 * 9,81               | m/s²  |
| $m$              | approx.                                                 | 95                     | g     |
| Case             | SKKT                                                    | A 46                   |       |
|                  | SKKT ...B                                               | A 48                   |       |
|                  | SKKH                                                    | A 47                   |       |



SKKT

SKKH



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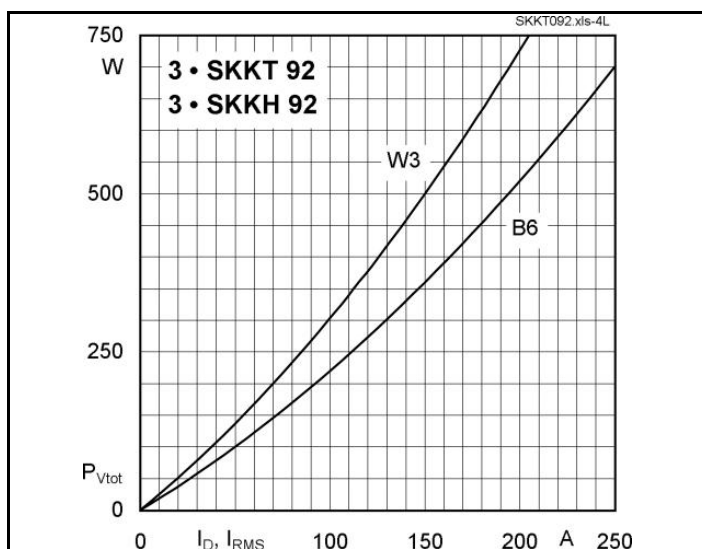


Fig. 4L Power dissipation of three modules vs. direct and rms current

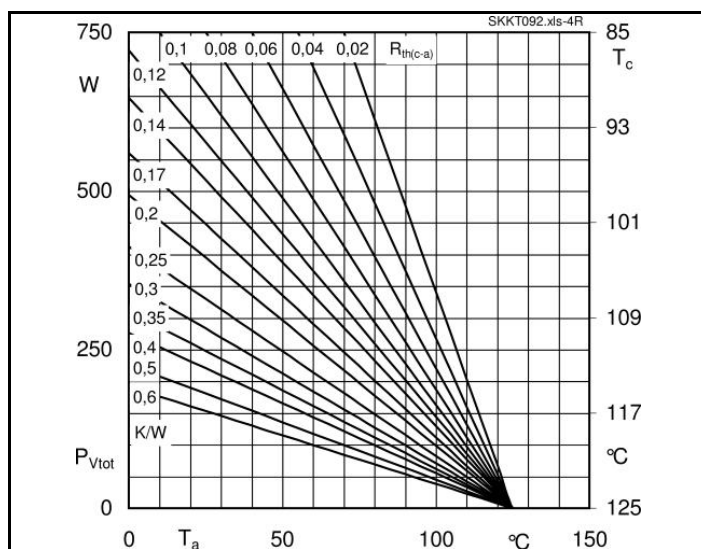


Fig. 4R Power dissipation of three modules vs. case temp.

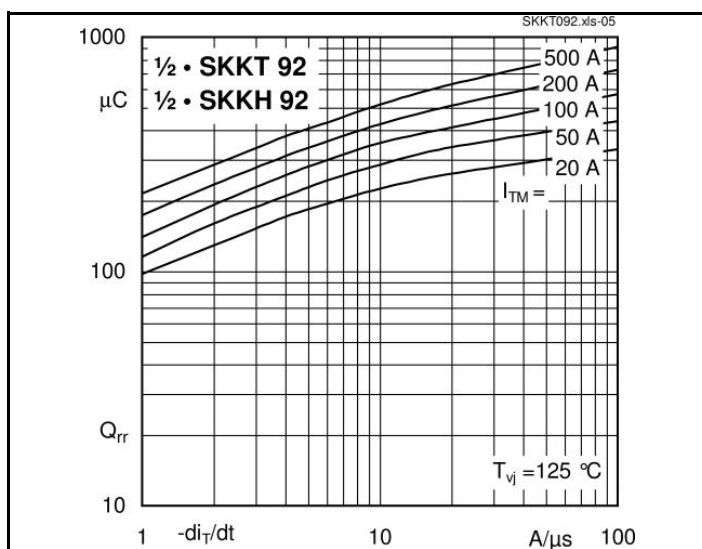


Fig. 5 Recovered charge vs. current decrease

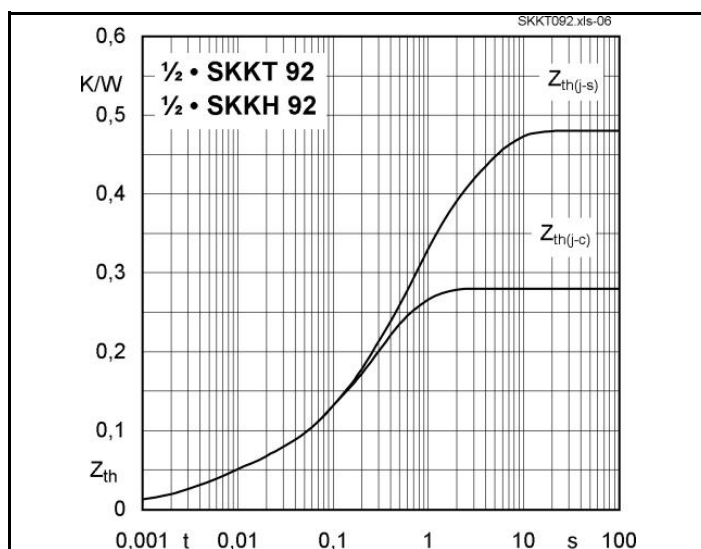


Fig. 6 Transient thermal impedance vs. time

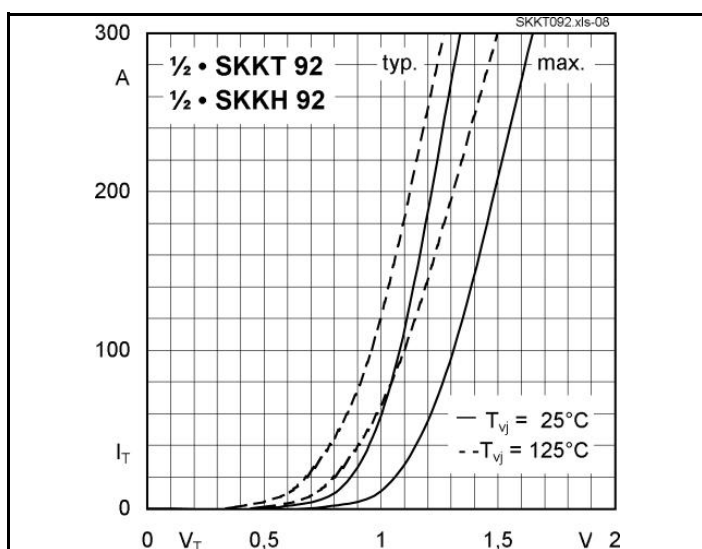


Fig. 7 On-state characteristics

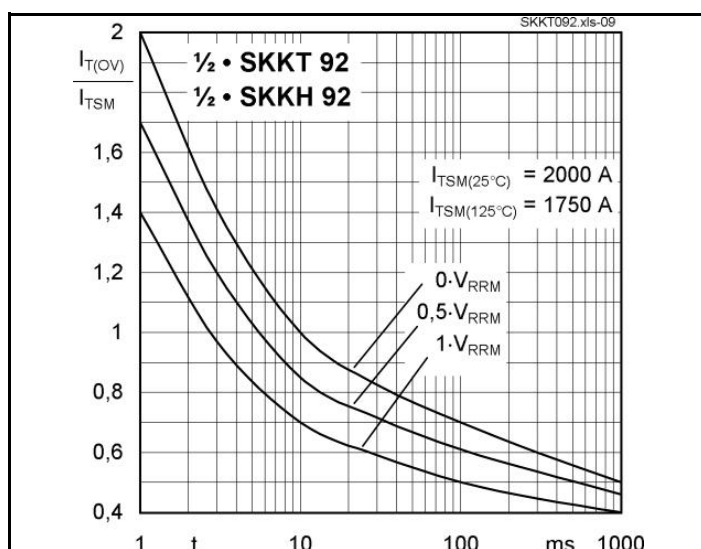
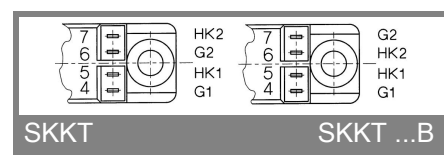
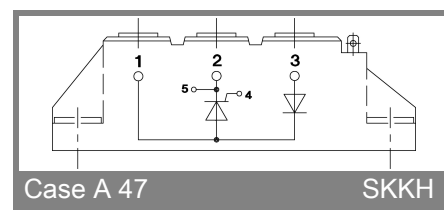
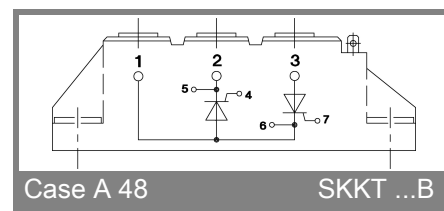
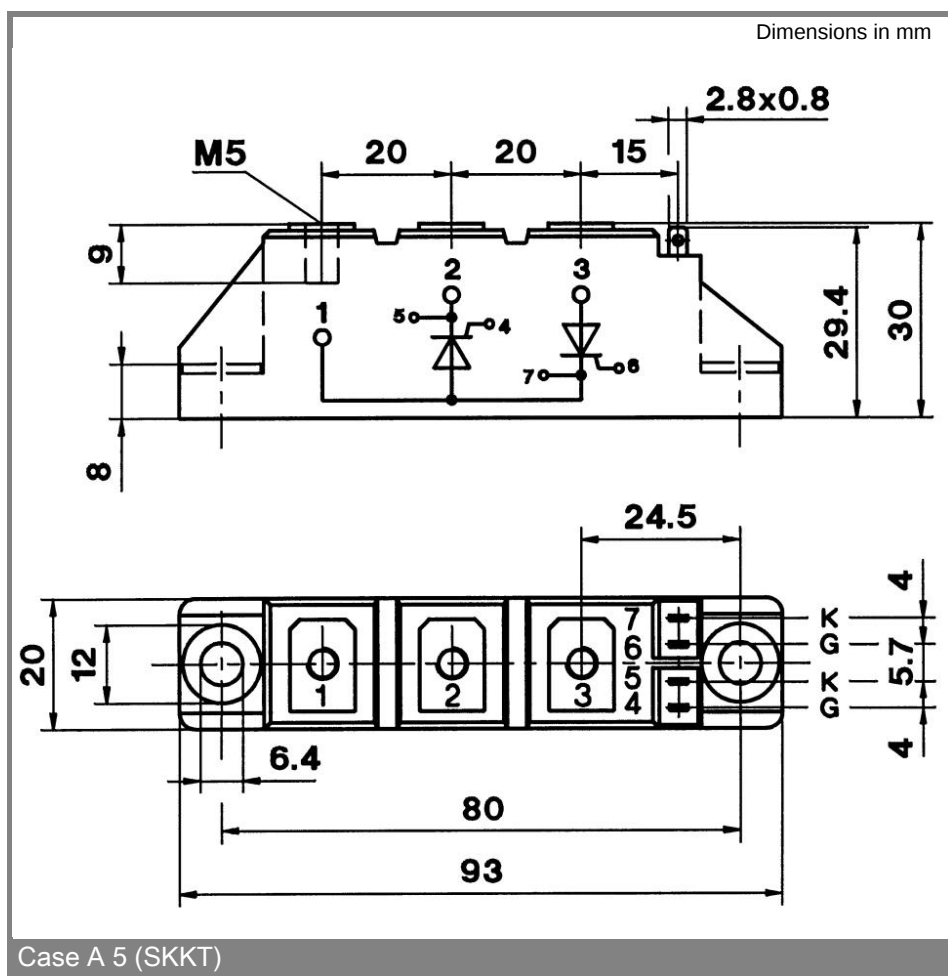
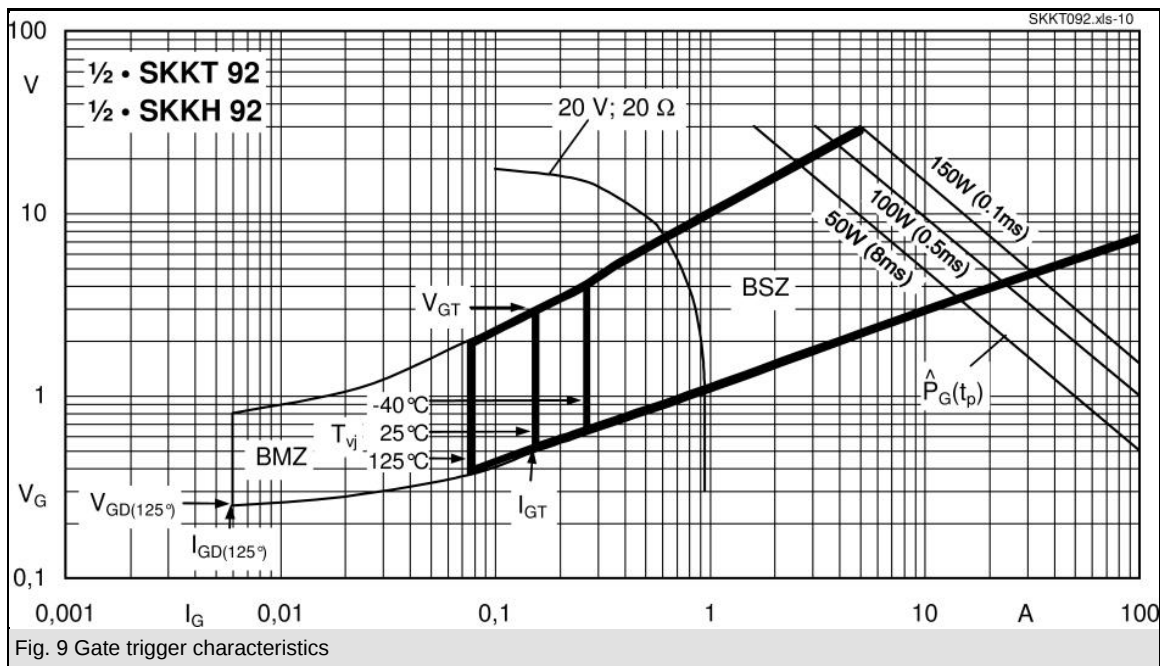


Fig. 8 Surge overload current vs. time



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